

GEMOLOGICAL INSTITUTE

## **ELECTRONIC COPY**

#### LABORATORY GROWN DIAMOND REPORT

### PROPORTIONS

**CLARITY CHARACTERISTICS** 

**KEY TO SYMBOLS** 

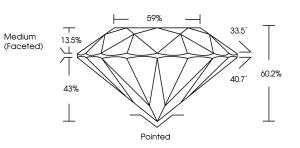
Red symbols indicate internal characteristics.

Green symbols indicate external characteristics.

August 13, 2024	
IGI Report Number	LG647482346
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	ROUND BRILLIANT
Measurements	8.93 - 8.95 X 5.38 MM
GRADING RESULTS	
Carat Weight	2.65 CARATS
Color Grade	D
Clarity Grade	VS 2
Cut Grade	IDEAL
ADDITIONAL GRADING I	NFORMATION

Polish	EXCELLEN					
Symmetry	EXCELLENT					
Fluorescence	NONE					
Inscription(s)	低到 LG647482346					

Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process. Type IIa



LG647482346

Report verification at igi.org

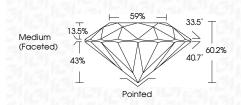


Sample Image Used

# 

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LABORATORY GROWN DIAMOND REPORT



#### ADDITIONAL GRADING INFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	低到 LG647482346
Comments: This Laboratory created by Chemical Vapo process. Type IIa	



D E F	GHIJ	Faint	Very Light	Light		
CLARITY	WS <sup>1 - 2</sup>	VS <sup>1-2</sup>	SI <sup>1-2</sup>	1 <sup>1-3</sup>		
Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included		





7482346	W	2.66 CARATS	٩	VS 2	IDEAL	60.2%	869	Medium (Facefed)	Pointed	EXCELLENT	EXCELLENT	NONE	<b>1691 LG647482346</b>	Comments: Na Locatory Grown Damond was cared by Chambed Vigoo Deposition (CND) growth process. Nipe IId
Au <b>gu</b> st 13, 2024 IGI Report No LG647482346 ROUND BRILLIANT	8.93 - 8.95 X 5.38 MM	Carat Weight	Color Grade	Clarity Grade	Cut Grade	Depth	Table	Girdle	Culet	Polish	Symmetry	Fluorescence	Inscription(s)	Comments: Comments: created by Characterial Vapor Deposit (CND) growth process: Type II g